TOSHIBA Power Transistor Module Silicon NPN Triple Diffused Type (Four Darlington Power Transistors in One)

MP4015

High Power Switching Applications Hammer Drive, Pulse Motor Drive Inductive Load Switching

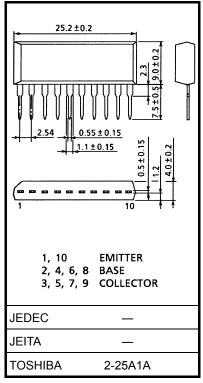
- Small package by full molding (SIP 10 pins)
- High collector power dissipation (4-device operation)
 PT = 4 W (Ta = 25°C)
- High collector current: IC(DC) = 5 A (max)
- High DC current gain: $h_{FE} = 1000$ (min) ($V_{CE} = 4$ V, $I_{C} = 3$ A)
- Zener diode included between collector and base.
- Unclamped inductive load energy: ES/B = 100 mJ (min)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	55	V	
Collector-emitter voltage		V _{CEO}	60 ± 10	V	
Emitter-base voltage		V _{EBO}	6	V	
Collector current	DC	IC	5	А	
Collector current	Pulse	I _{CP}	8		
Continuous base current		Ι _Β	0.5	Α	
Collector power dissipation (1-device operation)		PC	2.0	W	
Collector power dissipation (4-device operation)		P _T	4.0	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Industrial Applications

Unit: mm



Weight: 2.1 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

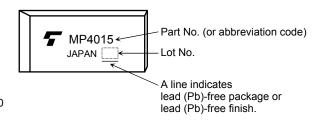
Array Configuration

2 4 4 6 8 8 10

 $R2 \approx 150 \Omega$

R1 ≈ 5 kΩ

Marking



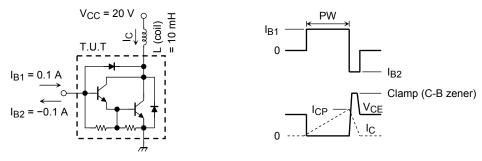


Thermal Characteristics

Characteristics	Symbol	Max	Unit	
Thermal resistance from junction to ambient	ΣR _{th (j-a)}	31.3	°C/W	
(4-device operation, Ta = 25°C)	3 (3)			
Maximum lead temperature for soldering purposes	TL	260	°C	
(3.2 mm from case for 10 s)				

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current		I _{CBO}	V _{CB} = 45 V, I _E = 0 A	_	_	10	μΑ	
Collector cut-off current		I _{CEO}	V _{CE} = 45 V, I _B = 0 A	_	_	10	μA	
Emitter cut-off current		I _{EBO}	V _{EB} = 6 V, I _C = 0 A	0.3	_	10	mA	
Collector-base breakdown voltage		V (BR) CBO	I _C = 10 mA, I _E = 0 A	50	_	70	V	
DC current gain		h _{FE (1)}	V _{CE} = 4 V, I _C = 1 A		_	_		
		h _{FE (2)}	V _{CE} = 4 V, I _C = 3 A	1000	_	_		
Saturation voltage	Collector-emitter	V _{CE} (sat) (1)	I _C = 1 A, I _B = 4 mA	_	0.9	1.4		
		V _{BE} (sat) (2)	I _C = 3 A, I _B = 10 mA	_	1.3	2.0		
	Base-emitter	V _{BE} (sat)	I _C = 1 A, I _B = 4 mA	_	1.6	2.0		
Base-emitter voltage		V _{BE}	V _{CE} = 4 V, I _B = 3 A	_	1.8	2.5	V	
Transition frequency		f _T	V _{CE} = 3 V, I _C = 0.5 A		7	_	MHz	
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0 A, f = 1 MHz	_	44	_	pF	
Switching time	Turn-on time	t _{on}	Output Input B1 20 μs B2 VCC = 30 V	_	0.6	_		
	Storage time	t _{stg}		_	4.2	_	μs	
	Fall time	t _f	$ _{B_1} = - _{B_2} = 10 \text{ mA, duty cycle} \le 1\%$	_	2.3	_		
Unclamped inductive load energy		E _{S/B}	Refer to Figure 1	100	_	_	mJ	



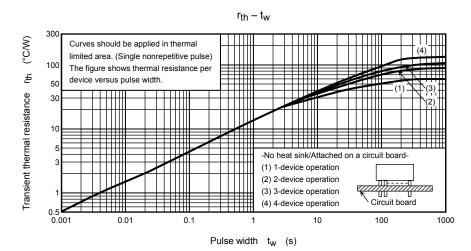
Note 1: Pulse width adjusted for desired I_{CP} (I_{CP} = 4.48 A min)

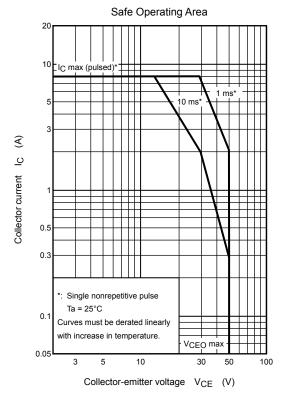
Note 2:
$$E_{S/B} = \frac{1}{2} L \cdot I_{CP} 2$$

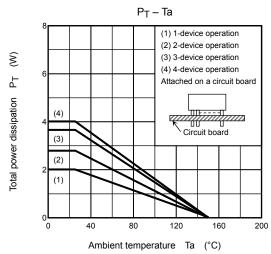
Figure 1 Measurement Circuit of Unclamped Inductive Load Energy E_{S/B}

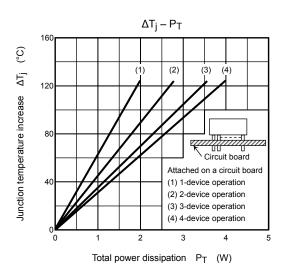
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